

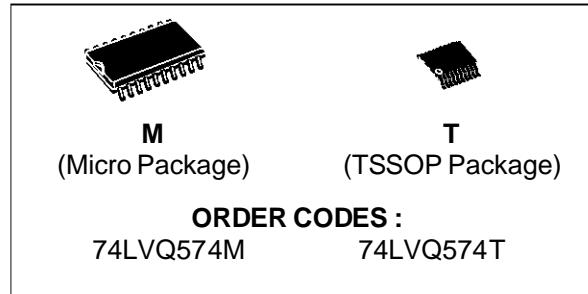
OCTAL D-TYPE FLIP FLOP  
WITH 3 STATE OUTPUT NON INVERTING

- HIGH SPEED:  
 $f_{MAX} = 180 \text{ MHz (TYP.)}$  at  $V_{CC} = 3.3V$
- COMPATIBLE WITH TTL OUTPUTS
- LOW POWER DISSIPATION:  
 $I_{CC} = 4 \mu\text{A (MAX.)}$  at  $T_A = 25^\circ\text{C}$
- LOW NOISE:  
 $V_{OLP} = 0.5 \text{ V (TYP.)}$  at  $V_{CC} = 3.3V$
- $75\Omega$  TRANSMISSION LINE DRIVING CAPABILITY
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OH}| = |I_{OL}| = 12 \text{ mA (MIN)}$
- PCI BUS LEVELS GUARANTEED AT 24 mA
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:  
 $V_{CC} (\text{OPR}) = 2V \text{ to } 3.6V$  (1.2V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 574
- IMPROVED LATCH-UP IMMUNITY

**DESCRIPTION**

The LVQ574 is a low voltage CMOS OCTAL D-TYPE FLIP FLOP with 3 STATE OUTPUT NON INVERTING fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology. It is ideal for low power and low noise 3.3V applications.

These 8 bit D-Type flip-flops are controlled by a clock input (CK) and an output enable input ( $\overline{OE}$ ).



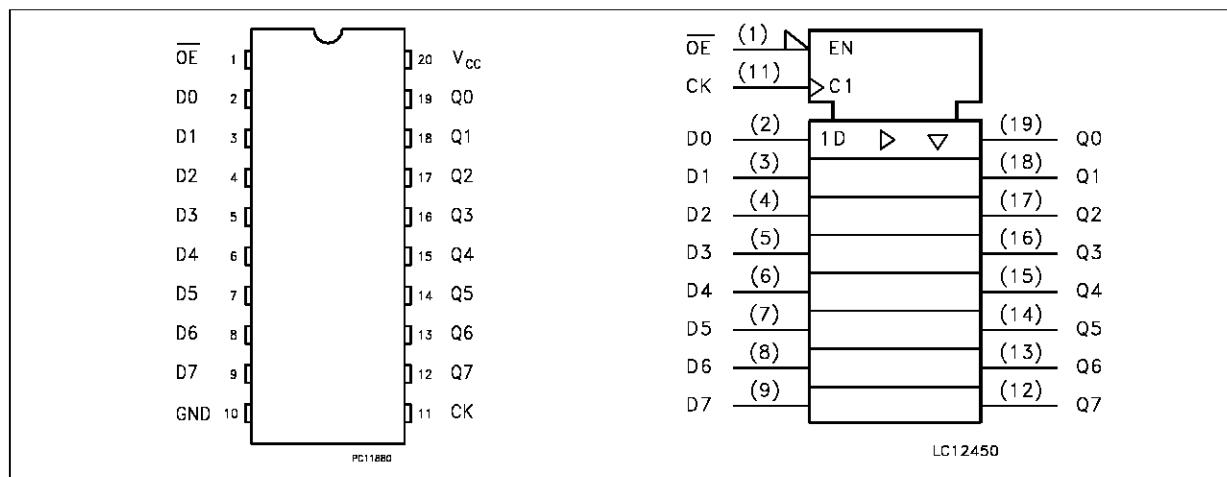
On the positive transition of the clock, the Q outputs will be set to logic state that were setup at the D inputs.

While the ( $\overline{OE}$ ) input is low, the 8 outputs will be in al normal logic state (high or low logic level) and while high level, the outputs will be in a high impedance state.

The output control does not affect the internal operation of flip flop, that is, the old data can be retained or the new data can be entered even while the outputs are off.

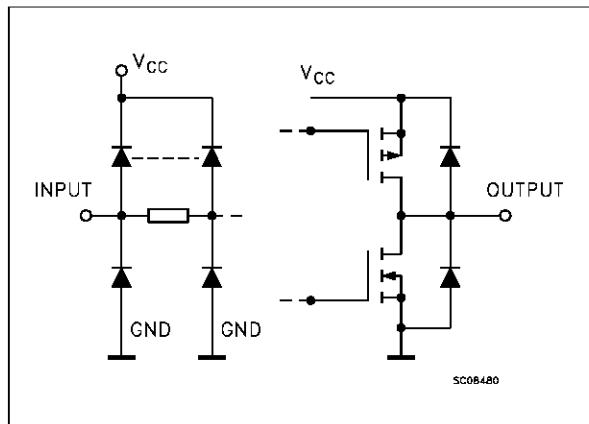
It has better speed performance at 3.3V than 5V LS-TTL family combined with the true CMOS low power consumpton.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

**PIN CONNECTION AND IEC LOGIC SYMBOLS**


## 74LVQ574

### INPUT AND OUTPUT EQUIVALENT CIRCUIT



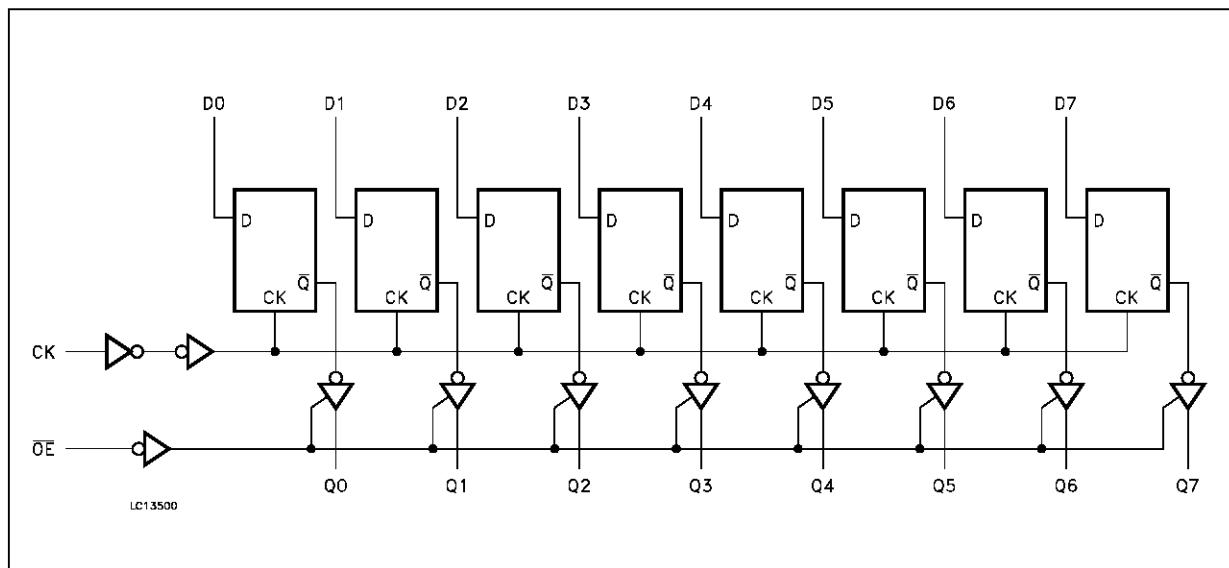
### PIN DESCRIPTION

| PIN No                               | SYMBOL          | NAME AND FUNCTION                         |
|--------------------------------------|-----------------|---|
| 1                                    | $\overline{OE}$ | 3 State Output Enable Input (Active LOW)  |
| 2, 3, 4,<br>5, 6, 7,<br>8, 9         | D0 to D7        | Data Inputs                               |
| 12, 13, 14,<br>15, 16, 17,<br>18, 19 | Q0 to Q7        | 3 State Outputs                           |
| 11                                   | CLOCK           | Clock Input (LOW to HIGH, edge triggered) |
| 10                                   | GND             | Ground (0V)                               |
| 20                                   | V <sub>CC</sub> | Positive Supply Voltage                   |

### TRUTH TABLE

| INPUTS          |    |   | OUTPUTS   |  |
|-----------------|----|---|-----------|--|
| $\overline{OE}$ | CK | D | Q         |  |
| H               | X  | X | Z         |  |
| L               |    | X | NO CHANGE |  |
| L               |    | L | L         |  |
| L               |    | H | H         |  |

### LOGIC DIAGRAMS



**ABSOLUTE MAXIMUM RATINGS**

| <b>Symbol</b>                       | <b>Parameter</b>                     | <b>Value</b>                  | <b>Unit</b> |
|-------------------------------------|--------------------------------------|-------------------------------|-------------|
| V <sub>CC</sub>                     | Supply Voltage                       | -0.5 to +7                    | V           |
| V <sub>I</sub>                      | DC Input Voltage                     | -0.5 to V <sub>CC</sub> + 0.5 | V           |
| V <sub>O</sub>                      | DC Output Voltage                    | -0.5 to V <sub>CC</sub> + 0.5 | V           |
| I <sub>IK</sub>                     | DC Input Diode Current               | ± 20                          | mA          |
| I <sub>OK</sub>                     | DC Output Diode Current              | ± 20                          | mA          |
| I <sub>O</sub>                      | DC Output Current                    | ± 50                          | mA          |
| I <sub>CC</sub> or I <sub>GND</sub> | DC V <sub>CC</sub> or Ground Current | ± 400                         | mA          |
| T <sub>STG</sub>                    | Storage Temperature                  | -65 to +150                   | °C          |
| T <sub>L</sub>                      | Lead Temperature (10 sec)            | 300                           | °C          |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

**RECOMMENDED OPERATING CONDITIONS**

| <b>Symbol</b>                  | <b>Parameter</b>   | <b>Value</b>         | <b>Unit</b> |
|--------------------------------|--|----------------------|-------------|
| V <sub>CC</sub>                | Supply Voltage (note 1)                                  | 2 to 3.6             | V           |
| V <sub>I</sub>                 | Input Voltage  | 0 to V <sub>CC</sub> | V           |
| V <sub>O</sub>                 | Output Voltage   | 0 to V <sub>CC</sub> | V           |
| T <sub>OP</sub>                | Operating Temperature:                                   | -40 to +85           | °C          |
| d <sub>t</sub> /d <sub>v</sub> | Input Rise and Fall Time (V <sub>CC</sub> = 3V) (note 2) | 0 to 10              | ns/V        |

1) Truth Table guaranteed: 1.2V to 3.6V

## DC SPECIFICATIONS

| Symbol           | Parameter                             | Test Conditions        |  | Value                  |      |       |              |      | Unit |  |
|------------------|---------------------------------------|------------------------|--|------------------------|------|-------|--------------|------|------|--|
|                  |                                       | V <sub>CC</sub><br>(V) |  | T <sub>A</sub> = 25 °C |      |       | -40 to 85 °C |      |      |  |
|                  |                                       |                        |  | Min.                   | Typ. | Max.  | Min.         | Max. |      |  |
| V <sub>IH</sub>  | High Level Input Voltage              | 3.0 to<br>3.6          |  | 2.0                    |      |       | 2.0          |      | V    |  |
| V <sub>IL</sub>  | Low Level Input Voltage               |                        |  |                        |      | 0.8   |              | 0.8  | V    |  |
| V <sub>OH</sub>  | High Level Output Voltage             | 3.0                    | V <sub>I</sub> <sup>(*)</sup> =<br>V <sub>IH</sub> or<br>V <sub>IL</sub><br>I <sub>O</sub> =-50 μA<br>I <sub>O</sub> =-12 mA<br>I <sub>O</sub> =-24 mA | 2.9                    | 2.99 |       | 2.9          |      | V    |  |
| V <sub>OL</sub>  | Low Level Output Voltage              |                        |  | 2.58                   |      |       | 2.48         |      |      |  |
|                  |                                       |                        |  |                        |      |       | 2.2          |      |      |  |
| I <sub>I</sub>   | Input Leakage Current                 | 3.6                    | V <sub>I</sub> = V <sub>CC</sub> or GND  |                        |      | ±0.1  |              | ±1   | μA   |  |
| I <sub>OZ</sub>  | 3 State Output Leakage Current        | 3.6                    | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub><br>V <sub>O</sub> = V <sub>CC</sub> or GND   |                        |      | ±0.25 |              | ±2.5 | μA   |  |
| I <sub>CC</sub>  | Quiescent Supply Current              | 3.6                    | V <sub>I</sub> = V <sub>CC</sub> or GND  |                        |      | 4     |              | 40   | μA   |  |
| I <sub>OLD</sub> | Dynamic Output Current<br>(note 1, 2) | 3.6                    | V <sub>OHD</sub> = 0.8 V max   |                        |      |       | 36           |      | mA   |  |
| I <sub>OHD</sub> |                                       |                        | V <sub>OHD</sub> = 2 V min   |                        |      |       | -25          |      | mA   |  |

1) Maximum test duration 2ms, one output loaded at time

2) Incident wave switching is guaranteed on transmission lines with impedances as low as 50 Ω.

## DYNAMIC SWITCHING CHARACTERISTICS

| Symbol            | Parameter                                    | Test Conditions        |                        | Value                  |      |      |              |      | Unit |  |
|-------------------|--|------------------------|------------------------|------------------------|------|------|--------------|------|------|--|
|                   |  | V <sub>CC</sub><br>(V) |                        | T <sub>A</sub> = 25 °C |      |      | -40 to 85 °C |      |      |  |
|                   |  |                        |                        | Min.                   | Typ. | Max. | Min.         | Max. |      |  |
| V <sub>O LP</sub> | Dynamic Low Voltage Quiet Output (note 1, 2) | 3.3                    | C <sub>L</sub> = 50 pF |                        | 0.5  | 0.8  |              |      | V    |  |
| V <sub>O LV</sub> |  |                        |                        | -0.8                   | -0.6 |      |              |      |      |  |
| V <sub>IHD</sub>  | Dynamic High Voltage Input (note 1, 3)       | 3.3                    |                        |                        |      | 2    |              |      | V    |  |
| V <sub>ILD</sub>  | Dynamic Low Voltage Input (note 1, 3)        | 3.3                    |                        | 0.8                    |      |      |              |      |      |  |

1) Worstcase package

2) Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V, (n-1) outputs switching and one output at GND

3) max number of data inputs (n) switching. (n-1) switching 0V to 3.3V. Inputs under test switching: 3.3V to threshold (V<sub>ILD</sub>), 0V to threshold (V<sub>IHD</sub>). f=1MHz

**AC ELECTRICAL CHARACTERISTICS** ( $C_L = 50 \text{ pF}$ ,  $R_L = 500 \Omega$ , Input  $t_r = t_f = 3 \text{ ns}$ )

| Symbol                                 | Parameter                                 | Test Condition         |  | Value                  |      |       |              |      | Unit |  |
|--|---|------------------------|--|------------------------|------|-------|--------------|------|------|--|
|  |   | V <sub>CC</sub><br>(V) |  | T <sub>A</sub> = 25 °C |      |       | -40 to 85 °C |      |      |  |
|  |   |                        |  | Min.                   | Typ. | Max.  | Min.         | Max. |      |  |
| t <sub>PLH</sub><br>t <sub>PHL</sub>   | Propagation Delay Time<br>CK to Q         | 2.7                    |  |                        | 7.5  | 17.0  |              | 18.0 | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 6.0  | 11.0  |              | 12.0 |      |  |
| t <sub>P LZ</sub><br>t <sub>PHZ</sub>  | Output Disable Time                       | 2.7                    |  |                        | 8.0  | 20.0  |              | 21.0 | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 6.5  | 14.0  |              | 15.0 |      |  |
| t <sub>P ZL</sub><br>t <sub>PZH</sub>  | Output Enable Time                        | 2.7                    |  |                        | 8.0  | 18.0  |              | 19.0 | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 6.5  | 12..0 |              | 13.0 |      |  |
| t <sub>w</sub>                         | Clock pulse Width, HIGH                   | 2.7                    |  |                        | 2.0  | 5.0   |              | 6.0  | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 1.5  | 4.0   |              | 4.0  |      |  |
| t <sub>sL</sub><br>t <sub>sH</sub>     | Setup Time D to LE<br>HIGH or LOW         | 2.7                    |  |                        | 0.0  | 2.5   |              | 3.0  | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 0.0  | 2.0   |              | 2.5  |      |  |
| t <sub>hL</sub><br>t <sub>hH</sub>     | Hold Time Q to CK<br>HIGH or LOW          | 2.7                    |  |                        | 0.0  | 2.5   |              | 3.0  | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 0.0  | 2.0   |              | 2.5  |      |  |
| f <sub>MAX</sub>                       | Maximum Clock<br>Frequency                | 2.7                    |  | 80                     | 150  |       | 70           |      | MHz  |  |
|  |   | 3.3 <sup>(*)</sup>     |  | 100                    | 180  |       | 90           |      |      |  |
| t <sub>OSLZ</sub><br>t <sub>OSHL</sub> | Output to Output Skew<br>Time (note 1, 2) | 2.7                    |  |                        | 0.5  | 1.0   |              | 1.5  | ns   |  |
|  |   | 3.3 <sup>(*)</sup>     |  |                        | 0.5  | 1.0   |              | 1.5  |      |  |

1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW

2) Parameter guaranteed by design

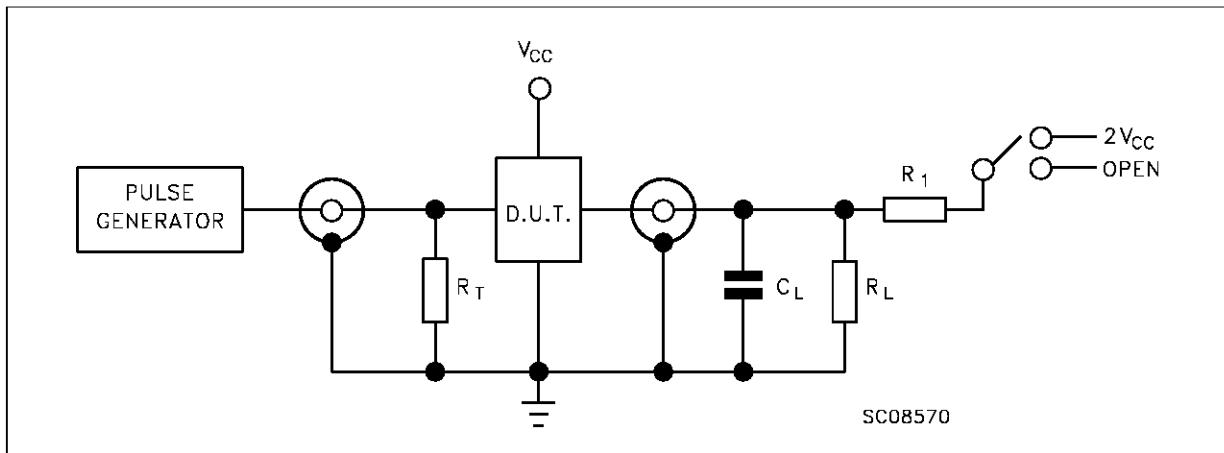
(\*) Voltage range is 3.3V ± 0.3V

**CAPACITIVE CHARACTERISTICS**

| Symbol           | Parameter                                 | Test Conditions        |                          | Value                  |      |      |              |      | Unit |  |
|------------------|---|------------------------|--------------------------|------------------------|------|------|--------------|------|------|--|
|                  |   | V <sub>CC</sub><br>(V) |                          | T <sub>A</sub> = 25 °C |      |      | -40 to 85 °C |      |      |  |
|                  |   |                        |                          | Min.                   | Typ. | Max. | Min.         | Max. |      |  |
| C <sub>IN</sub>  | Input Capacitance                         | 3.3                    |                          |                        | 4    |      |              |      | pF   |  |
| C <sub>OUT</sub> | Output Capacitance                        | 3.3                    |                          |                        | 10   |      |              |      | pF   |  |
| C <sub>PD</sub>  | Power Dissipation<br>Capacitance (note 1) | 3.3                    | f <sub>IN</sub> = 10 MHz |                        | 15   |      |              |      | pF   |  |

1) C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I<sub>CC(Opr)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>IN</sub> + I<sub>CC</sub>/n (per circuit)

## TEST CIRCUIT

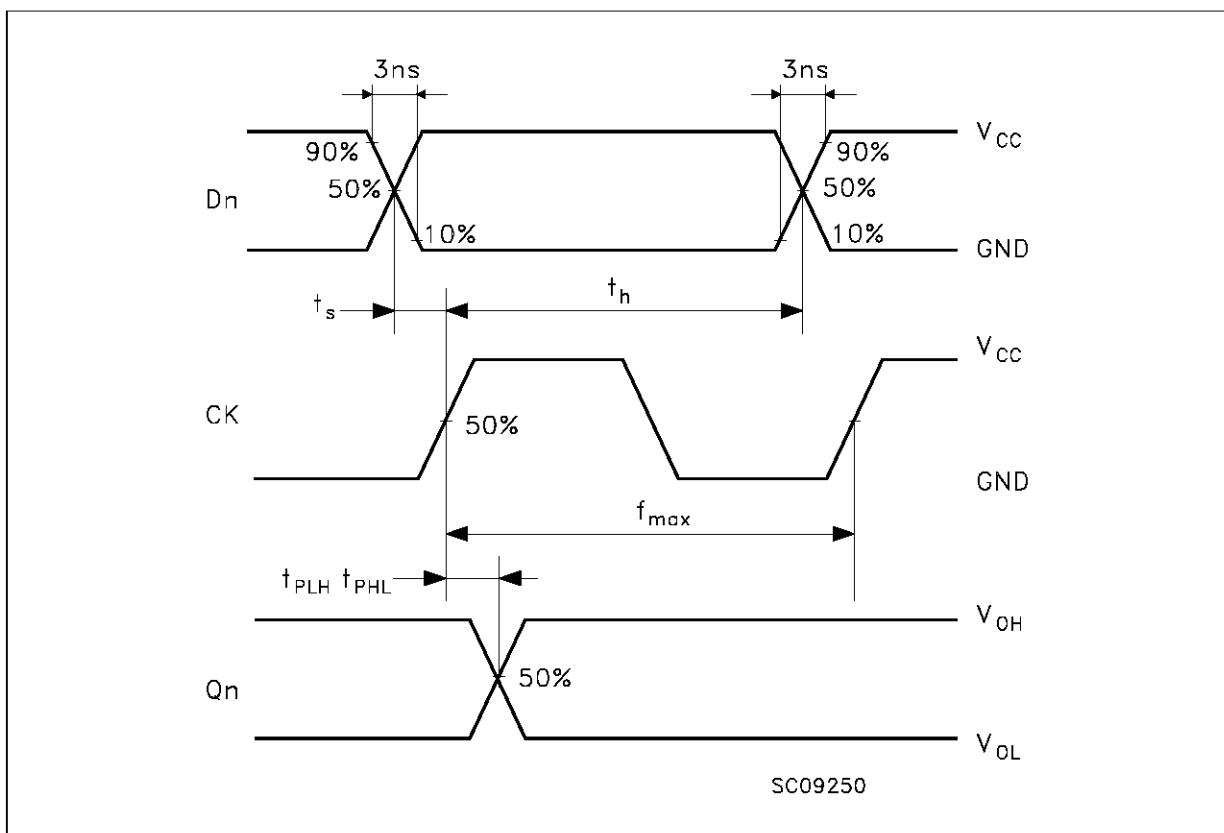


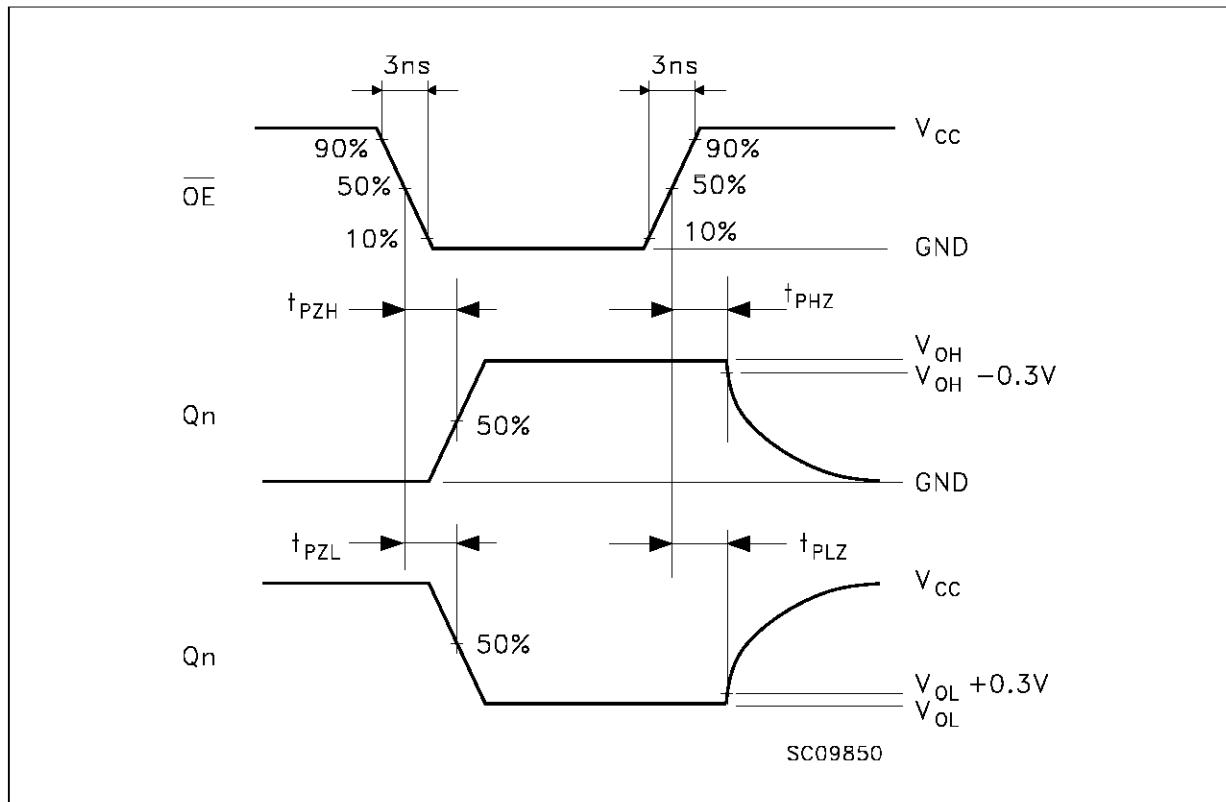
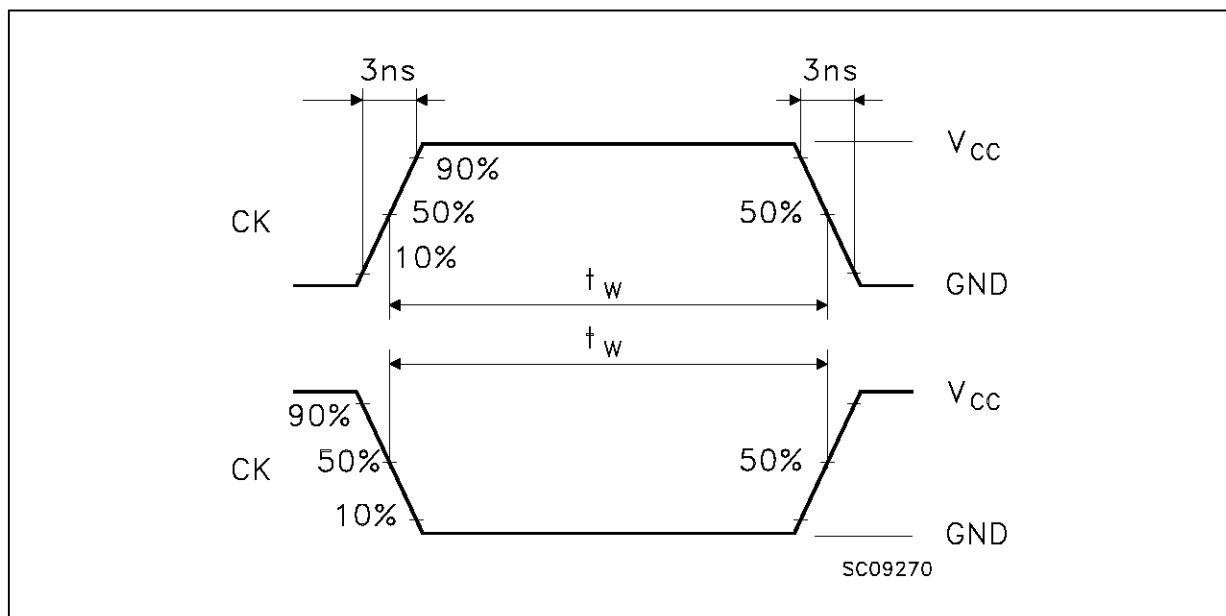
| TEST               | SWITCH    |
|--------------------|-----------|
| $t_{PLH}, t_{PHL}$ | Open      |
| $t_{PZL}, t_{PLZ}$ | $2V_{CC}$ |
| $t_{PZH}, t_{PHZ}$ | Open      |

$C_L = 50 \text{ pF}$  or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 500\Omega$  or equivalent

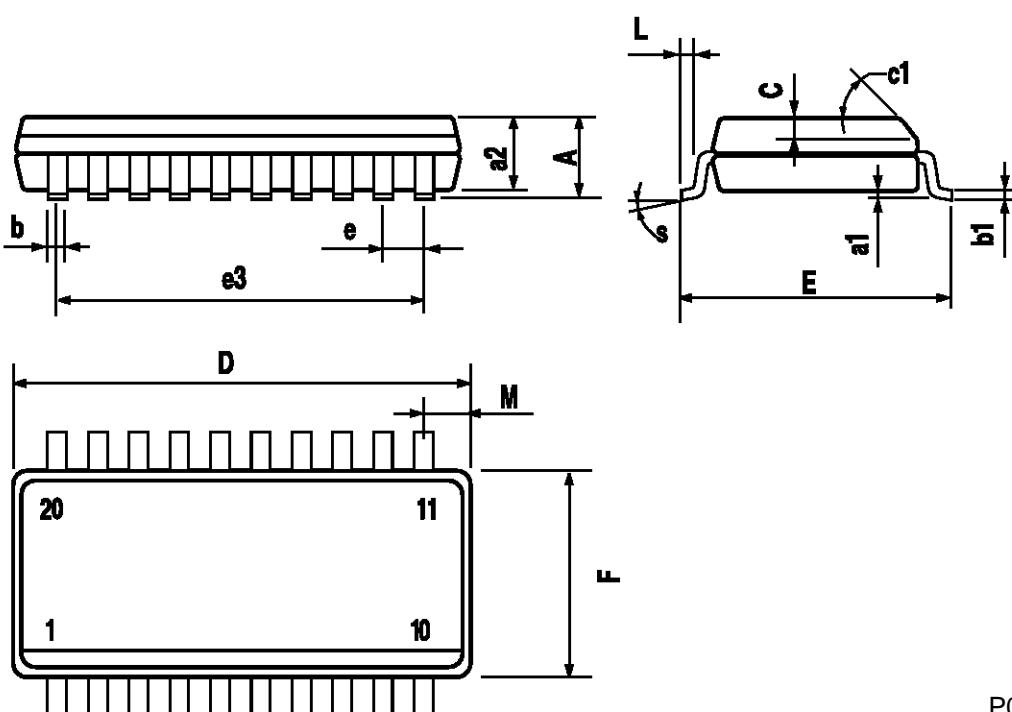
$R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

WAVEFORM 1: PROPAGATION DELAYS, SETUP AND HOLD TIMES ( $f=1\text{MHz}$ ; 50% duty cycle)

**WAVEFORM 2: OUTPUT ENABLE AND DISABLE TIMES (f=1MHz; 50% duty cycle)****WAVEFORM 3: PULSE WIDTH**

## SO20 MECHANICAL DATA

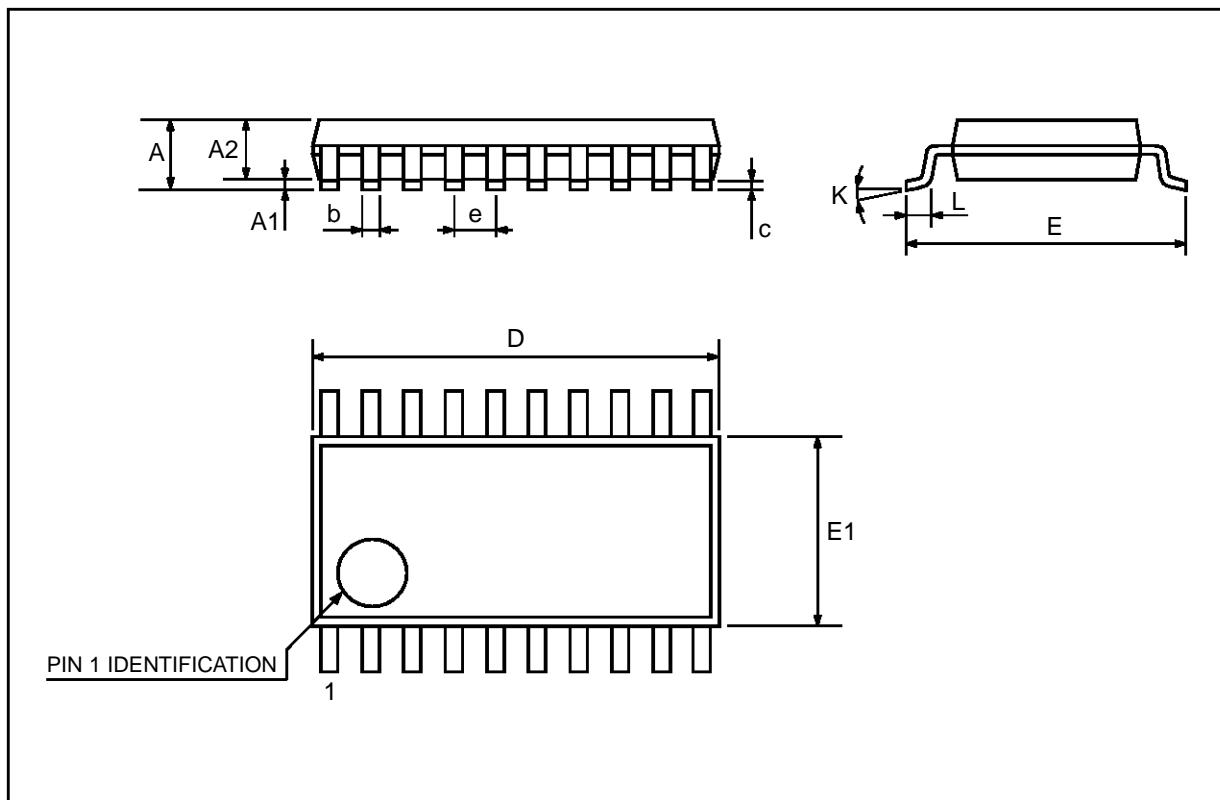
| DIM. | mm    |            |       | inch  |       |       |
|------|-------|------------|-------|-------|-------|-------|
|      | MIN.  | TYP.       | MAX.  | MIN.  | TYP.  | MAX.  |
| A    |       |            | 2.65  |       |       | 0.104 |
| a1   | 0.10  |            | 0.20  | 0.004 |       | 0.007 |
| a2   |       |            | 2.45  |       |       | 0.096 |
| b    | 0.35  |            | 0.49  | 0.013 |       | 0.019 |
| b1   | 0.23  |            | 0.32  | 0.009 |       | 0.012 |
| C    |       | 0.50       |       |       | 0.020 |       |
| c1   |       | 45° (typ.) |       |       |       |       |
| D    | 12.60 |            | 13.00 | 0.496 |       | 0.512 |
| E    | 10.00 |            | 10.65 | 0.393 |       | 0.419 |
| e    |       | 1.27       |       |       | 0.050 |       |
| e3   |       | 11.43      |       |       | 0.450 |       |
| F    | 7.40  |            | 7.60  | 0.291 |       | 0.299 |
| L    | 0.50  |            | 1.27  | 0.19  |       | 0.050 |
| M    |       |            | 0.75  |       |       | 0.029 |
| S    |       | 8° (max.)  |       |       |       |       |



P013L

### TSSOP20 MECHANICAL DATA

| DIM. | mm   |          |      | inch   |            |        |
|------|------|----------|------|--------|------------|--------|
|      | MIN. | TYP.     | MAX. | MIN.   | TYP.       | MAX.   |
| A    |      |          | 1.1  |        |            | 0.433  |
| A1   | 0.05 | 0.10     | 0.15 | 0.002  | 0.004      | 0.006  |
| A2   | 0.85 | 0.9      | 0.95 | 0.335  | 0.354      | 0.374  |
| b    | 0.19 |          | 0.30 | 0.0075 |            | 0.0118 |
| c    | 0.09 |          | 0.2  | 0.0035 |            | 0.0079 |
| D    | 6.4  | 6.5      | 6.6  | 0.252  | 0.256      | 0.260  |
| E    | 6.25 | 6.4      | 6.5  | 0.246  | 0.252      | 0.256  |
| E1   | 4.3  | 4.4      | 4.48 | 0.169  | 0.173      | 0.176  |
| e    |      | 0.65 BSC |      |        | 0.0256 BSC |        |
| K    | 0°   | 4°       | 8°   | 0°     | 4°         | 8°     |
| L    | 0.50 | 0.60     | 0.70 | 0.020  | 0.024      | 0.028  |



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